S102T01/S102T02 S202T01/S202T02

■ Features

- 1. Low profile type (height:16mm)
- 2. Built-in zero-cross circuit (\$102T02/\$202T02)
- 3. RMS ON-state current I_T (rms): MAX. 2A (T_a≤40°C)
- Recognized by UL, file No.E94758
 Approved by CSA, No.LR63705

■ Applications

- 1. Programmable controllers
- 2. Air conditioners
- 3. Copiers
- 4. Automatic vending machines

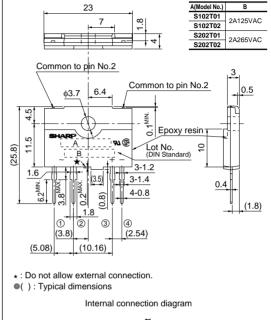
■ Absolute Maximum Ratings $(T_a=25^{\circ}C)$									
	Paramet	er	Symbol	Rating	Unit				
	Forward current		I_F	50	mA				
Input	Reverse voltage		V_R	6	V				
Output	RMS ON-state current		$I_{T(rms)}$	*1 2	A				
	*2 Peak one cycle	surge current	I _{surge}	20	A				
	Repetitive peak OFF-state voltage	S102T01		400					
		S102T02		400					
		S202T01	V_{DRM}	600	V				
		S202T02		600					
	Non-repetitive peak OFF-state voltage	S102T01		400					
		S102T02		400					
		S202T01	V_{DSM}		V				
		S202T02		600					
	Critical rate of rise o	f ON-state current	dI _T /dt	50	A/μs				
	Operating fr	equency	f	45 to 65	Hz				
Operating temperature			T_{opr}	-25 to +100	°C				
Storage temperature			T_{stg}	-30 to +125	°C				
*3 Isolation voltage			V _{iso (rms)}	3.0	kV				
*4 Soldering temperature		T_{sol}	260	°C					

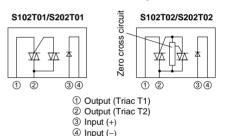
- *1 Refer to Fig.2, Fig.3
- *2 60Hz sine wave, start at T_i=25°C
- *3 Isolation voltage measuring method
 - (1) Dielectric withstand voltage tester with zero cross circuit shall be used
 - (2) The applied voltage waveform shall be sine wave
 - (3) Voltage shall be applied between input and output (Input and output terminals shall be shorted respectively)
- (4) 40 to 60% RH, AC 60Hz, for 1minute
- *4 For 10s

Low Profile Type Solid State Relays

■ Outline Dimensions

(Unit: mm)





■ Model line-up

	For 100V lines	For 200V lines
No zero-cross circuit	S102T01	S202T01
Built-in zero-cross circuit	S102T02	S202T02

Ω

ms

ms

1

10

1

10

10

Transfer characteristics

Isolation resistance

Turn-on

Turn-off

time

time

S102T01

S102T02

S202T01

S202T02

S102T01

S102T02

S202T01

S202T02

■ Electro-optical Characteristics								
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit		
Forward voltage	V_F	$I_F=20mA$	-	1.2	1.4	V		
Reverse current	I_R	V _R =3V	-	=	1×10 ⁻⁴	A		
Repetitive peak OFF-state current	I_{DRM}	$V_D = V_{DRM}$	-	=	1×10 ⁻⁴	A		
ON-state voltage	$V_{T (rms)}$	I _{T (rms)} =2A, Resistance load, I _F =20mA	-	_	1.7	V		
Holding current	I_H	_	_	_	25	mA		
Critical rate of rise of OFF-state voltage	dV/dt	$V_D=2/3V_{DRM}$	30	_	_	V/µs		
Critical rate of rise of OFF-state voltage at commutation	(dV/dt) _C	$T_j=125$ °C, $V_D=2/3V_{DRM}$, $dI_t/dt=-2.5A/ms$	4	_	_	V/µs		
Minimum \$102T01/\$202T01	т	$V_D=12V, R_L=30\Omega$		_	8	mA		
trigger current \$102T02/\$202T02	1FT	$V_D=6V, R_L=30\Omega$	_					
Zero cross voltage S102T02/S202T02	Vox	I _F =8mA	-	_	35	V		
	Parameter Forward voltage Reverse current Repetitive peak OFF-state current ON-state voltage Holding current Critical rate of rise of OFF-state voltage Critical rate of rise of OFF-state voltage at commutation Minimum S102T01/S202T01 trigger current S102T02/S202T02	$ \begin{array}{c cccc} Parameter & Symbol \\ \hline Forward voltage & V_F \\ Reverse current & I_R \\ Repetitive peak OFF-state current & I_{DRM} \\ \hline ON-state voltage & V_{T (rms)} \\ Holding current & I_H \\ Critical rate of rise of OFF-state voltage & dV/dt \\ \hline Critical rate of rise of OFF-state voltage at commutation & (dV/dt)_C \\ \hline Minimum & S102T01/S202T01 \\ trigger current & S102T02/S202T02 \\ \hline \end{array} $	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		

DC500V, 40 to 60% RH

 $V_{D \text{ (rms)}}=100V, AC50Hz, I_{T \text{ (rms)}}=2A,$

Resistance load, I_F=20mA

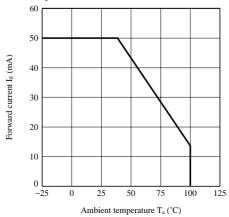
 $V_{D \text{ (rms)}}=200V, AC50Hz, I_{T \text{ (rms)}}=2A,$

Resistance load, I_F=20mA

 $V_{D (rms)}$ =100V, AC50Hz, $I_{T (rms)}$ =2A, Resistance load, I_{F} =20mA

 $V_{D (rms)}$ =200V, AC50Hz, $I_{T (rms)}$ =2A, Resistance load, I_{F} =20mA

Fig.1 Forward Current vs. Ambient Temperature



 R_{iso}

 t_{on}

 $t_{\rm off}$

Fig.2 RMS ON-state Current vs. Ambient Temperature

 1×10^{10}

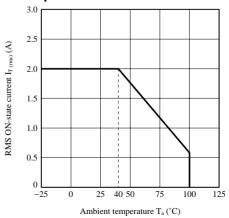


Fig.3 Forward Current vs. Forward Voltage

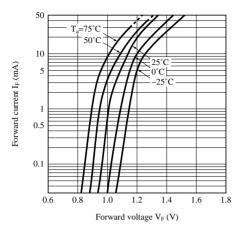


Fig.5 Minimum Trigger Current vs. Ambient Temperature (Typical Value)

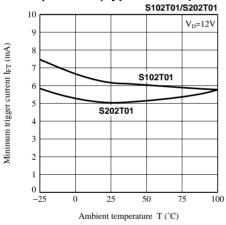


Fig.7 Maximum ON-state Power Dissipation vs. RMS ON-state Current (Typical Value)

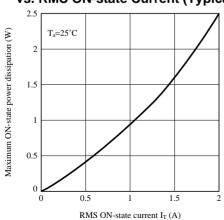


Fig.4 Surge Current vs. Power-on Cycle

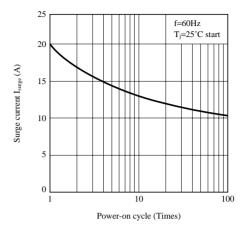


Fig.6 Minimum Trigger Current vs. Ambient Temperature (Typical Value)

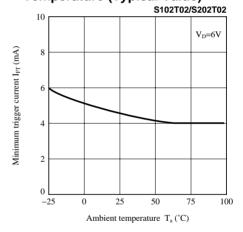


Fig.8 Repetitive Peak OFF-state Current vs. Ambient Temperature

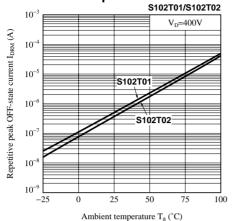
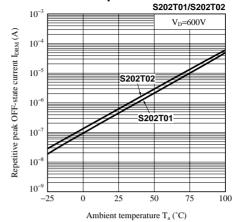


Fig.9 Repetitive Peak OFF-state Current vs.
Ambient Temperature



NOTICE

- The circuit application examples in this publication are provided to explain representative applications of SHARP
 devices and are not intended to guarantee any circuit design or license any intellectual property rights. SHARP takes
 no responsibility for any problems related to any intellectual property right of a third party resulting from the use of
 SHARP's devices.
- Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device. SHARP
 reserves the right to make changes in the specifications, characteristics, data, materials, structure, and other contents
 described herein at any time without notice in order to improve design or reliability. Manufacturing locations are
 also subject to change without notice.
- Observe the following points when using any devices in this publication. SHARP takes no responsibility for damage
 caused by improper use of the devices which does not meet the conditions and absolute maximum ratings to be used
 specified in the relevant specification sheet nor meet the following conditions:
 - (i) The devices in this publication are designed for use in general electronic equipment designs such as:
 - --- Personal computers
 - --- Office automation equipment
 - --- Telecommunication equipment [terminal]
 - --- Test and measurement equipment
 - --- Industrial control
 - --- Audio visual equipment
 - --- Consumer electronics
 - (ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection with equipment that requires higher reliability such as:
 - --- Transportation control and safety equipment (i.e., aircraft, trains, automobiles, etc.)
 - --- Traffic signals
 - --- Gas leakage sensor breakers
 - --- Alarm equipment
 - --- Various safety devices, etc.
 - (iii)SHARP devices shall not be used for or in connection with equipment that requires an extremely high level of reliability and safety such as:
 - --- Space applications
 - --- Telecommunication equipment [trunk lines]
 - --- Nuclear power control equipment
 - --- Medical and other life support equipment (e.g., scuba).
- If the SHARP devices listed in this publication fall within the scope of strategic products described in the Foreign Exchange and Foreign Trade Law of Japan, it is necessary to obtain approval to export such SHARP devices.
- This publication is the proprietary product of SHARP and is copyrighted, with all rights reserved. Under the copyright laws, no part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, for any purpose, in whole or in part, without the express written permission of SHARP. Express written permission is also required before any use of this publication may be made by a third party.
- Contact and consult with a SHARP representative if there are any questions about the contents of this publication.